NSN 5961-01-394-4898

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-394-4898 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.460 inches **Overall Height:** 0.040 inches **Overall Width:** 0.460 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Common anode configuration//the ceramic case contains beryllium oxide-handle and dispose iaw hazmat procedures; junction pattern arrangement: pin **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**